

DMP2305U-7 Datasheet

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| DiGi Electronics Part Number | DMP2305U-7-DG |
|------------------------------|--|
| Manufacturer | Diodes Incorporated |
| Manufacturer Product Number | DMP2305U-7 |
| Description | MOSFET P-CH 20V 4.2A SOT23-3 |
| Detailed Description | P-Channel 20 V 4.2A (Ta) 1.4W (Ta) Surface Mount SOT-23-3 |
| | |

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Purchase and inquiry

| Manufacturer Product Number: | Manufacturer: |
|---|---|
| DMP2305U-7 | Diodes Incorporated |
| Series: | Product Status: |
| - | Active |
| FET Type: | Technology: |
| P-Channel | MOSFET (Metal Oxide) |
| Drain to Source Voltage (Vdss): | Current - Continuous Drain (Id) @ 25°C: |
| 20 V | 4.2A (Ta) |
| Drive Voltage (Max Rds On, Min Rds On): | Rds On (Max) @ ld, Vgs: |
| 1.8V, 4.5V | 60mOhm @ 4.2A, 4.5V |
| Vgs(th) (Max) @ ld: | Gate Charge (Qg) (Max) @ Vgs: |
| 900mV @ 250µA | 7.6 nC @ 4.5 V |
| Vgs (Max): | Input Capacitance (Ciss) (Max) @ Vds: |
| ±8V | 727 pF @ 20 V |
| FET Feature: | Power Dissipation (Max): |
| - | 1.4W (Ta) |
| Operating Temperature: | Mounting Type: |
| -55°C ~ 150°C (TJ) | Surface Mount |
| Supplier Device Package: | Package / Case: |
| SOT-23-3 | TO-236-3, SC-59, SOT-23-3 |
| Base Product Number: | |
| DMP2305 | |

Environmental & Export classification

| RoHS Status: | Moisture Sensitivity Level (MSL): |
|------------------|-----------------------------------|
| ROHS3 Compliant | 1 (Unlimited) |
| REACH Status: | ECCN: |
| REACH Unaffected | EAR99 |
| HTSUS: | |
| 8541.29.0095 | |





DMP2305U

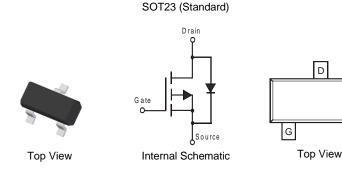
Features

- Low On-Resistance
 - 60mΩ @ V_{GS} = -4.5V
 - 90mΩ @ V_{GS} = -2.5V
 - 113mΩ @ V_{GS} = -1.8V
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

P-CHANNEL ENHANCEMENT MODE MOSFET

Mechanical Data

- Package: SOT23
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (@3)
- Terminals Connections: See Diagram Below
- Weight: 0.008 grams (Approximate)



Ordering Information (Note 4)

| Part Number | Qualification Package Packing | | king | |
|--------------|-------------------------------|------------------|------|-------------|
| r art Number | Quanication | T dekage | Qty. | Carrier |
| DMP2305U-7 | Standard | SOT23 (Standard) | 3000 | Tape & Reel |

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



Shanghai A/T Site

23P

Σ

23P = Product Type Marking Code YM = Date Code Marking for SAT (Shanghai Assembly/ Test Site) \overline{YM} = Date Code Marking for CAT (Chengdu Assembly/ Test Site) Y or \overline{Y} = Year (ex: J = 2022) M = Month (ex: 9 = September)

Date Code Key

| Date Code Key | | | | | | | | | | | | |
|---------------|------|--------|------|------|------|------|------|------|------|------|------|------|
| Year | 2009 | | 2022 | 2023 | 2024 | 2025 | 2026 | 2027 | 2028 | 2029 | 2030 | 2031 |
| Code | W | | J | К | L | М | N | 0 | Р | R | S | Т |
| | | | - | | | | | - | - | | , | • |
| | | і Г | - | | | | | | | | - | · · |
| Month | Jan | Feb | Mar | Apr | Мау | Jun | Jul | Aug | Sep | Oct | Nov | Dec |

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Maximum Ratings (@TA = +25°C, unless otherwise specified.)

| Characte | | Symbol | Value | Unit | |
|-----------------------------------|-----------------|--|------------------|--------------|---|
| Drain-Source Voltage | | | Vdss | -20 | V |
| Gate-Source Voltage | | | V _{GSS} | ±8 | V |
| Continuous Drain Current (Note 5) | Steady State | T _A = +25°C T _A = +70°C | lo | -4.2 -3.4 | А |
| Pulsed Drain Current (Note 6) | | | ldм | -10 | А |

Thermal Characteristics

| Characteristic | Symbol | Value | Unit |
|---|------------------|-------------|------|
| Power Dissipation (Note 5) | PD | 1.4 | W |
| Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ | R _{0JA} | 90 | °C/W |
| Operating and Storage Temperature Range | TJ, TSTG | -55 to +150 | °C |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition |
|--|--------------------|------|------|------|------|--|
| OFF CHARACTERISTICS (Note 7) | Cymser | | . 76 | шах | Unit | |
| Drain-Source Breakdown Voltage | BV _{DSS} | -20 | | _ | V | $V_{GS} = 0V, I_{D} = -250\mu A$ |
| Zero Gate Voltage Drain Current $T_J = +25^{\circ}C$ | IDSS | _ | | -1.0 | μA | $V_{DS} = -20V, V_{GS} = 0V$ |
| Gate-Source Leakage | Igss | _ | | ±100 | nA | $V_{GS} = \pm 8V, V_{DS} = 0V$ |
| ON CHARACTERISTICS (Note 7) | • | | | | | |
| Gate Threshold Voltage | VGS(TH) | -0.5 | _ | -0.9 | V | $V_{DS} = V_{GS}$, $I_D = -250 \mu A$ |
| | | | 45 | 60 | | VGS = -4.5V, ID = -4.2A |
| Static Drain-Source On-Resistance | RDS (ON) | _ | 60 | 90 | mΩ | V _{GS} = -2.5V, I _D = -3.4A |
| | | | 87 | 113 | | VGS = -1.8V, ID = -2.0A |
| Forward Transfer Admittance | Y _{FS} | _ | 9 | _ | S | $V_{DS} = -5V, I_D = -4A$ |
| DYNAMIC CHARACTERISTICS (Note 8) | - | | | | | · |
| Input Capacitance | Ciss | _ | 727 | — | pF | |
| Output Capacitance | Coss | _ | 69 | _ | pF | −V _{DS} = -20V, V _{GS} = 0V −f = 1.0MHz |
| Reverse Transfer Capacitance | Crss | _ | 64 | _ | pF | |
| Gate Resistance | Rg | _ | 23 | — | Ω | $V_{GS} = 0V, V_{DS} = 0V, f = 1.0MHz$ |
| SWITCHING CHARACTERISTICS | | | | | | |
| Total Gate Charge | Qg | _ | 7.6 | _ | nC | |
| Gate-Source Charge | Qgs | _ | 1.4 | _ | nC | VGS = -4.5V, VDS = -4V, ID = -3.5A |
| Gate-Drain Charge | Qgd | _ | 1.2 | — | nC | |
| Turn-On Delay Time | t _{D(ON)} | | 14.0 | | ns | |
| Turn-On Rise Time | tR | _ | 13.0 | _ | ns | $V_{DS} = -4V, V_{GS} = -4.5V,$ |
| Turn-Off Delay Time | tD(OFF) | _ | 53.8 | | ns | $R_L = 4\Omega, R_G = 6\Omega, I_D = -1A$ |
| Turn-Off Fall Time | tF | _ | 23.2 | | ns | |

Notes:

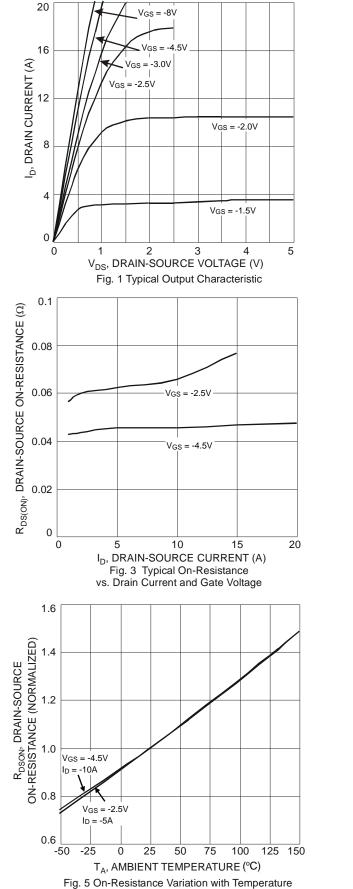
5. Device mounted on FR-4 PCB with 2oz. copper and test pulse width t \leq 10s.

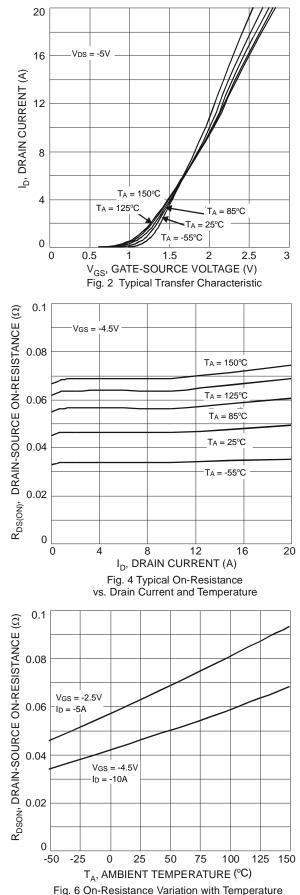
Repetitive rating, pulse width limited by junction temperature.
Short duration pulse test used to minimize self-heating effect.

Short duration pulse test used to minimize self-nearing en
Guaranteed by design. Not subject to production testing.



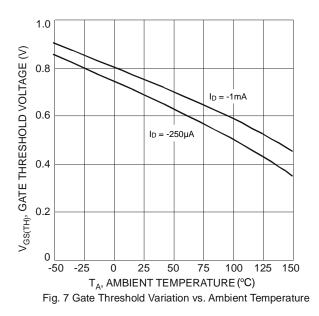
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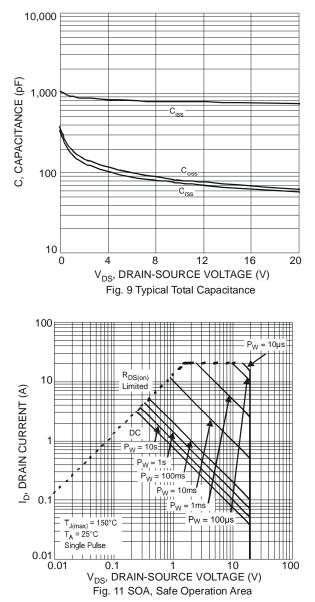


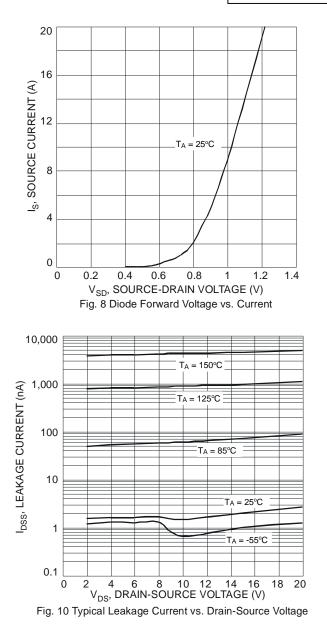




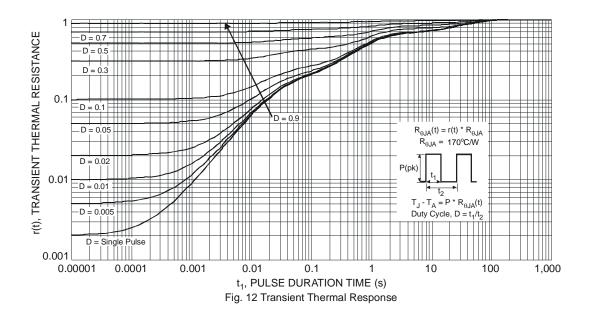
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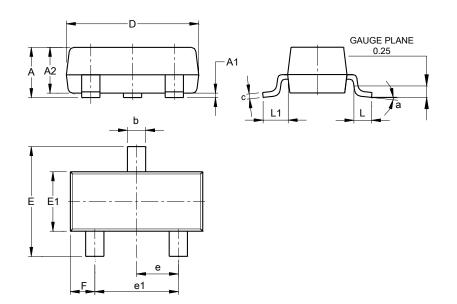


SOT23 (Standard)



Package Outline Dimensions

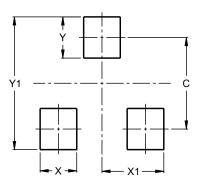
Please see http://www.diodes.com/package-outlines.html for the latest version.



| SOT23 (Standard) | | | | | | | | |
|------------------|--------|---------|-------|--|--|--|--|--|
| Dim | Min | Max | Тур | | | | | |
| Α | 0.90 | 1.15 | 1.025 | | | | | |
| A1 | 0.00 | 0.10 | 0.05 | | | | | |
| A2 | 0.85 | 1.10 | 0.975 | | | | | |
| b | 0.30 | 0.51 | 0.40 | | | | | |
| C | 0.080 | 0.202 | 0.11 | | | | | |
| D | 2.80 | 3.00 | 2.90 | | | | | |
| E | 2.25 | 2.55 | 2.40 | | | | | |
| E1 | 1.20 | 1.40 | 1.30 | | | | | |
| e | 0.89 | 1.03 | 0.915 | | | | | |
| e1 | 1.78 | 2.05 | 1.83 | | | | | |
| F | 0.40 | 0.60 | 0.535 | | | | | |
| L1 | 0.45 | 0.61 | 0.55 | | | | | |
| L | 0.25 | 0.55 | 0.40 | | | | | |
| а | 0° | 8° | | | | | | |
| All | Dimens | ions in | mm | | | | | |

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23 (Standard)

| Dimensions | Value (in mm) |
|------------|---------------|
| С | 2.0 |
| Х | 0.8 |
| X1 | 1.35 |
| Y | 0.9 |
| Y1 | 2.9 |



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